



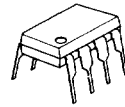
DUAL HIGH CURRENT OPERATIONAL AMPLIFIER

GENERAL DESCRIPTION

The NJM4556A integrated circuit is a high-gain, high output current dual operational amplifier capable of driving $\pm 70\text{mA}$ into $150\ \Omega$ loads ($\pm 10.5\text{V}$ output voltage), and operating low supply voltage ($V^+/V^- = \pm 2\text{V} \sim$).

The NJM4556A combines many of the features of the popular NJM4558 as well as having the capability of driving $150\ \Omega$ loads. In addition, the wide band-width, low noise, high slew rate and low distortion of the NJM4556A make it ideal for many audio, telecommunications and instrumentation applications.

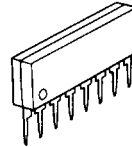
PACKAGE OUTLINE



NJM4556AD



NJM4556AM



NJM4556AL

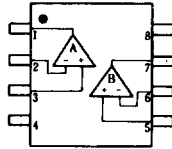


NJM4556AV

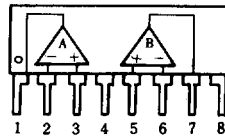
FEATURES

- Operating Voltage ($\pm 2\text{V} \sim \pm 18\text{V}$)
- High Output Current ($I_o = 70\text{mA}$)
- Slew Rate ($3\text{V}/\mu\text{s}$ typ.)
- Gain Band Width Product (8MHz typ.)
- Package Outline DIP8, DMP8, SIP8, SSOP8
- Bipolar Technology

PIN CONFIGURATION



NJM4556AD
NJM4556AM
NJM4556AV

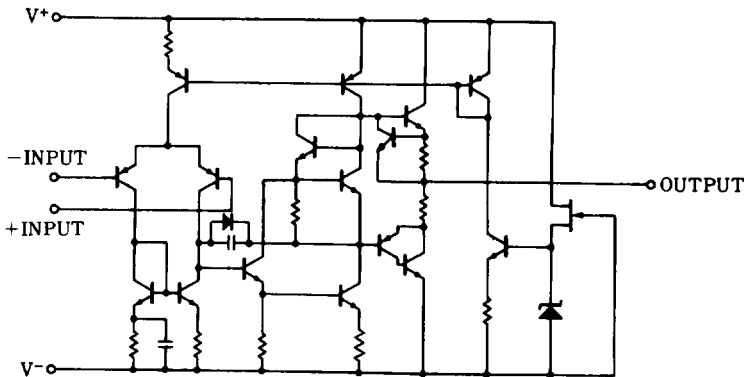


NJM4556AL

PIN FUNCTION

1. A OUTPUT
2. A - INPUT
3. A + INPUT
4. V^-
5. B + INPUT
6. B - INPUT
7. B OUTPUT
8. V^+

EQUIVALENT CIRCUIT (1/2 Shown)





■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V ⁺ /V ⁻	±18	V
Differential Input Voltage	V _{ID}	±30	V
Input Voltage	V _I	±15 (note)	V
Power Dissipation	P _D	(DIP8) 700	mW
		(DMP8) 300	mW
		(SSOP8) 250	mW
		(SIP8) 800	mW
Operating Temperature Range	T _{opr}	-20~+75	°C
Storage Temperature Range	T _{stg}	-40~+125	°C

(note) For supply voltage less than ±15V, the absolute maximum input voltage is equal to the supply voltage.

■ ELECTRICAL CHARACTERISTICS (NJM4556AD/NJM4556AS)

(V⁺/V⁻=±15V Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	V _{IO}	R _S ≤ 10kΩ	—	0.5	6.0	mV
Input Offset Current	I _{IO}		—	5	60	nA
Input Bias Current	I _B		—	50	500	nA
Input Resistance	R _{IN}		0.3	5	—	MΩ
Large Signal Voltage Gain	A _V	R _L ≥ 2kΩ, V _O = ±10V	86	100	—	dB
Maximum Output Voltage Swing 1	V _{OM1}	R _L ≥ 2kΩ	±12	±13.5	—	V
Maximum Output Voltage Swing 2	V _{OM2}	R _L ≥ 150Ω	±10.5	±11	—	V
Input Common Mode Voltage Range	V _{ICM}		±13.5	±14	—	V
Common Mode Rejection Ratio	CMR	R _S ≤ 10kΩ	70	90	—	dB
Supply Voltage Rejection Ratio	SVR	R _S ≤ 10kΩ	76.5	90	—	dB
Operating Current	I _{CC}		—	9	12	mA
Slew Rate	SR		—	3	—	V/μS
Gain Bandwidth Product	GB		—	8	—	MHz

■ ELECTRICAL CHARACTERISTICS (NJM4556AM/NJM4556AV)

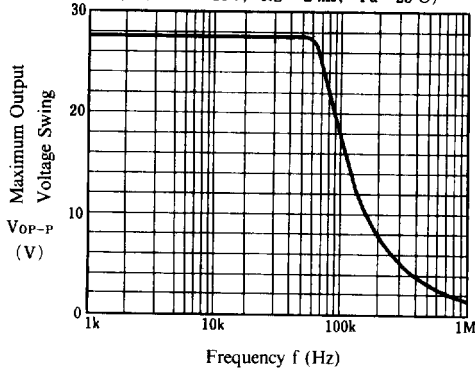
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	V _{IO}	R _S ≤ 10kΩ	—	0.5	6.0	mV
Input Offset Current	I _{IO}		—	5	60	nA
Input Bias Current	I _B		—	50	500	nA
Large Signal Voltage Gain	A _V	R _L ≥ 2kΩ, V _O = ±10V	86	100	—	dB
Maximum Output Voltage Swing 1	V _{OM1}	V _{IN+} =4V, V _{IN-} =3V, V ⁺ =9V I _{source} =40mA	7.5	—	—	V
Maximum Output Voltage Swing 2	V _{OM2}	V _{IN+} =3V, V _{IN-} =4V, V ⁺ =9V I _{sink} =40A	—	—	2.1	V
Input Common Mode Voltage Range 1	V _{ICM1}	V ⁺ =9V, V _L	—	—	1.5	V
Input Common Mode Voltage Range 2	V _{ICM2}	V ⁺ =9V, V _H	8	—	—	V
Common Mode Rejection Ratio	CMR	R _S ≤ 10kΩ	70	90	—	dB
Supply Voltage Rejection Ratio	SVR	R _S ≤ 10kΩ	76.5	90	—	dB
Supply Current	I _{CC}	V ⁺ =9V	—	8	12	mA
Slew Rate	SR		—	3	—	V/μS
Gain Bandwidth Product	GB		—	8	—	MHz



■ TYPICAL CHARACTERISTICS

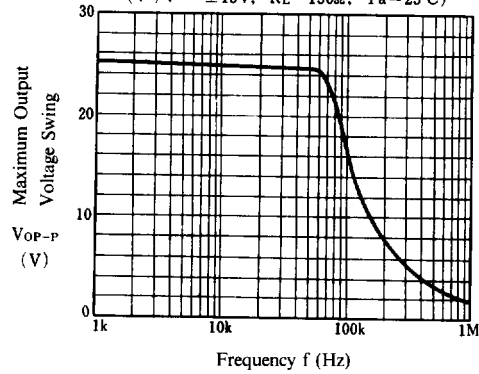
Maximum Output Voltage Swing vs. Frequency

($V^+/V^- = \pm 15V$, $R_L = 2\text{ k}\Omega$, $T_a = 25^\circ\text{C}$)



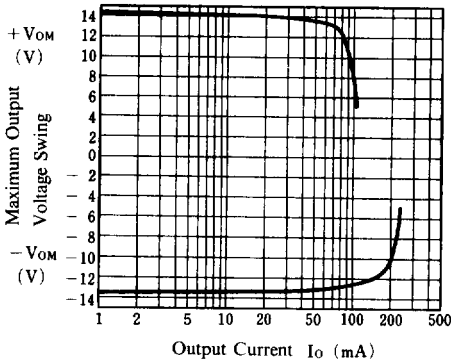
Maximum Output Voltage Swing vs. Frequency

($V^+/V^- = \pm 15V$, $R_L = 150\Omega$, $T_a = 25^\circ\text{C}$)



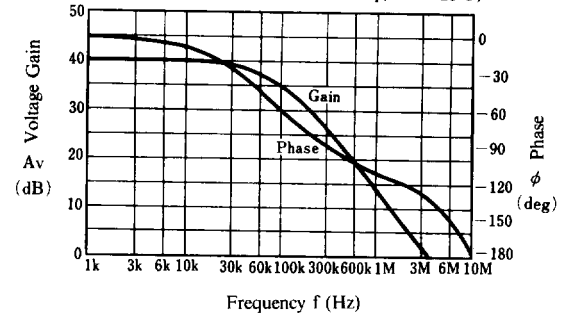
Maximum Output Voltage Swing vs. Output Current

($V^+/V^- = \pm 15V$, $T_a = 25^\circ\text{C}$)



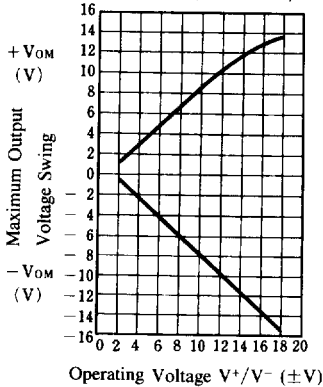
Voltage Gain, Phase Shift vs. Frequency

($V^+/V^- = \pm 15V$, $R_L = 2\text{ k}\Omega$, 40dBamp , $T_a = 25^\circ\text{C}$)



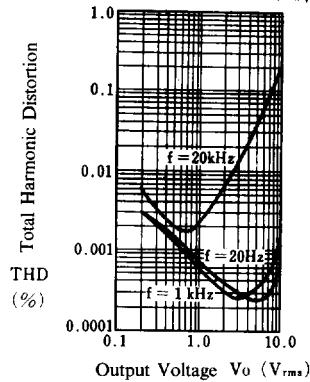
Maximum Output Voltage Swing vs. Operating Voltage

($R_L = 150\Omega$, $T_a = 25^\circ\text{C}$)



Total Harmonic Distortion vs. Output Voltage

($V^+/V^- = \pm 15V$, $R_L = 200\Omega$, $G_{ain} = 30\text{dB}$, $T_a = 25^\circ\text{C}$)



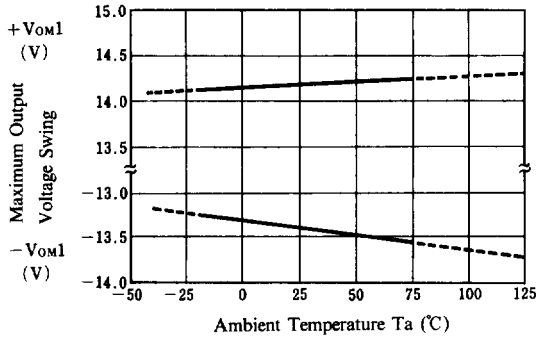
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TYPICAL CHARACTERISTICS

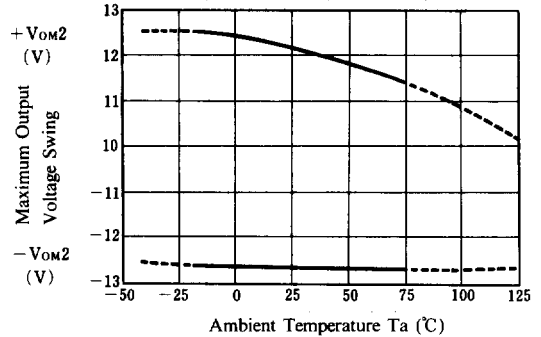
Maximum Output Voltage Swing vs. Temperature

($V^+/V^- = \pm 15V$, $R_L = 2\text{ k}\Omega$)



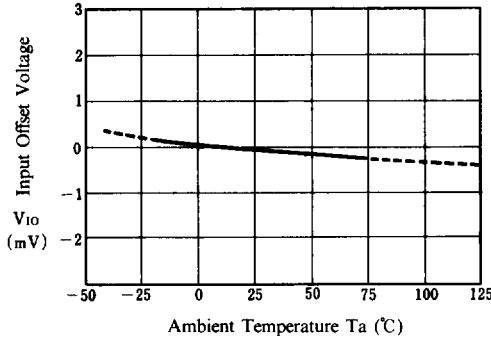
Maximum Output Voltage Swing vs. Temperature

($V^+/V^- = \pm 15V$, $R_L = 150\Omega$)



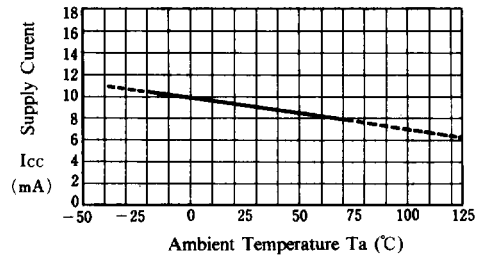
Input Offset Voltage vs. Temperature

($V^+/V^- = \pm 15V$)



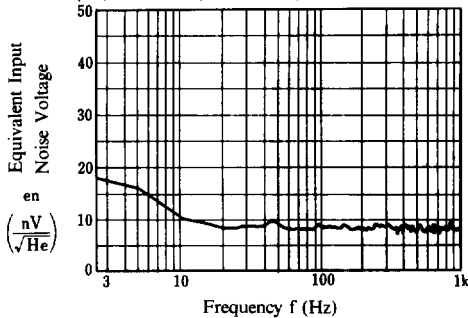
Supply Current vs. Temperature

($V^+/V^- = \pm 15V$)



Equivalent Input Noise Voltage vs. Frequency

($V^-/V^+ = \pm 15V$, $R_s = 100\Omega$, $A_v = 40\text{ dB}$, $T_a = 25^\circ\text{C}$)



Operating Current vs. Operating Voltage

($T_a = 25^\circ\text{C}$)

